

General Bridge Rectifiers



Voltage: 600~1000 2.0 Package: ABS Volts **Current:** Ampers Diagram: **Features** NH'S Standard Rectifier Chip Technology Low Forward Voltage Drop For High Efficiency Low Leakage Current For High Reliability High Surge Capability For High Reliability **Mechanical Data** Case: Molded With UL-94 ClassV-0 Recognized, RoHS-Compliant Polarity: Look At The Diagram And Polarity On The Right Terminals: Tin Plated Leads, Solderable Per J-STD-002 And JESD22-B102 **Typical Applications** Switch Mode Power Supplies (SMPS) Polarity: Fast Chargers LED Driver And Monitor Lighting

Single Phase, Half Wave, 60Hz, Resistive Or Inductive Load. For Capacitive Load, Derate Current By 20%

Automotive Electronics And Charging Posts

Maximum Ratings (Ta=25℃ Unless Otherwise Specified)						
Parameter	Test Conditions	Symbol	ABS 206	ABS 208	ABS 210	Unit
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	600	800	1000	V
Maximum RMS Voltag		V_{RMS}	420	560	700	V
Maximum DC Blocking Voltage		V_{DC}	600	800	1000	V
Maximum Average Forward Rectified Current		$I_{F(AV)}$		2.0		A
Peak Forward Surge Current Per Diode	8.3ms Single Half Sine-wave Superimposed On Rate Load	I_{FSM}		60		A
Current Squared Time Per Diode	t< 8.3ms	I^2t		14.9		A ² sec

Electrical Characteristcs (Ta=25°C Unless Otherwise Specified)						
Parameter Test Conditions		Symbol	ABS 206	ABS 208	ABS 210	Unit
Instaneous Forward Voltage Per Diode	I_F = 2.0 A	$\mathbf{V_F}$	1.0		V	
Maximum DC Reverse Current at Rated DC Blocking Voltage	$Ta=25^{\circ}C$, $V_R=VRRM$ $Ta=125^{\circ}C$, $V_R=VRRM*80\%$	I_{RRM}	5 200		uA uA	
Typical Junction Capacitance Per Diode	4 V,1MHz	$C_{\rm J}$ 25		pF		

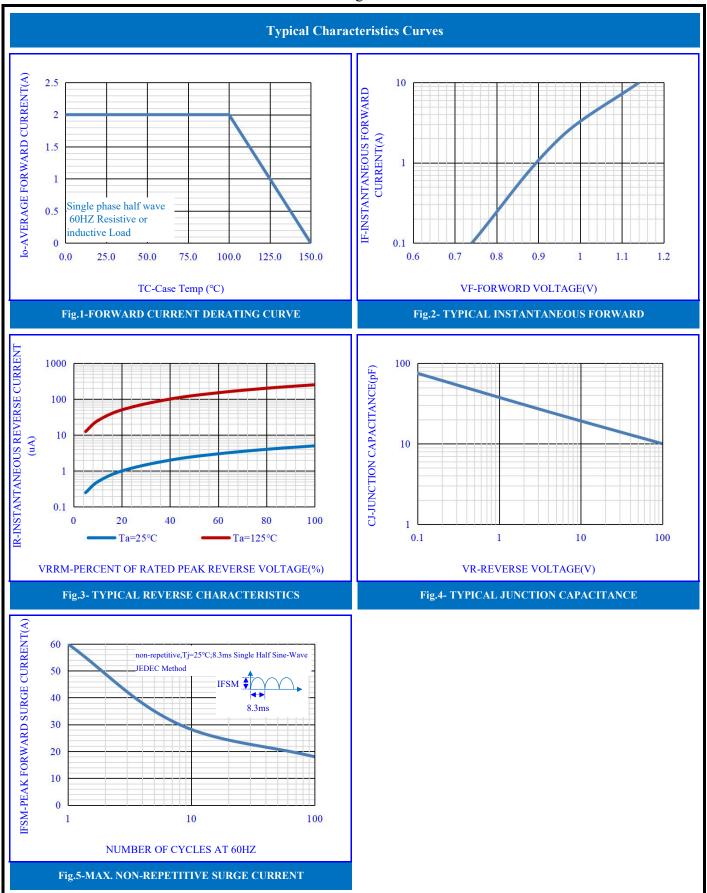
Thermal Characteristcs (Ta=25°C Unless Otherwise Specified)						
Parameter	Test Conditions	Symbol	ABS 206	ABS 208	ABS 210	Unit
Operating Junction Temperature Range T _J -55~150			°			
Storage Temperature Range		T _{STD}	-55~150		C	
Thermal Resistance Junction To Ambient	Still Air Environment	D	(0.0			
With Steady-State With $Ta=25^{\circ}C$ R_{0JA} 60.0		°C/W				
Thermal Resistance Junction-Case	Device Mounted On	D	16.0		C/W	
With Steady-State	1 in 2 FR-4 Board With 2oz. Copper	$R_{\theta JC}$		16.0		
Notes: 1.Pulse Test: 300 Us Pulse Width.1% Duty Cycle						

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Pb RoHS COMPLIANT

ABS206 THRU ABS210

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Max.

0.2126

0.1772

0.2579

0.0571

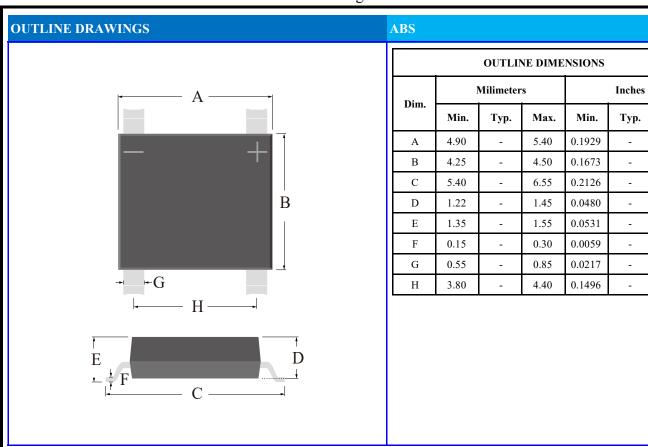
0.0610

0.0118

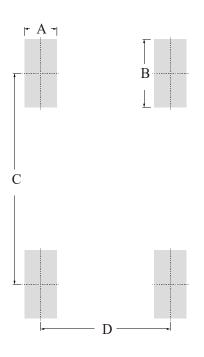
0.0335

0.1732

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RECOMMEDNED LAYOUT DRAWINGS



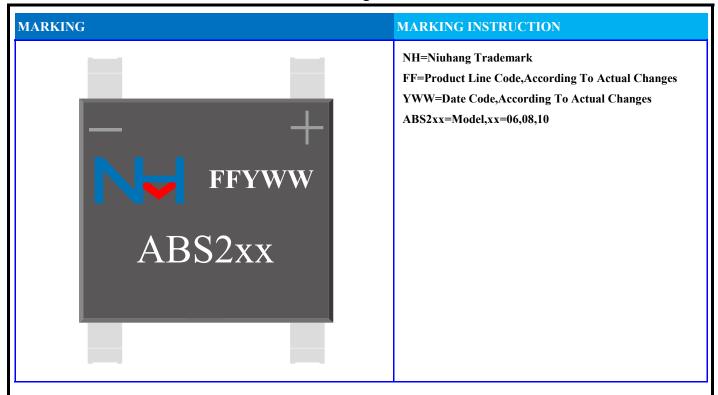
ABS

OUTLINE DIMENSIONS						
Dim.	1	Milimeter	Inches			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.
A	-	1.00	-	-	0.0394	-
В	-	2.00	-	-	0.0787	1
С	-	6.20	-	-	0.2441	-
D	-	4.00	-	-	0.1575	-





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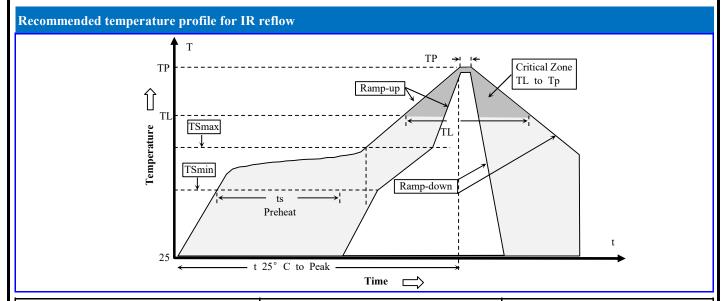
PACKING INFORMATION						
Package Type	Package Code	Productor Weight Approx(g/Pcs)	Package Method	Quantity (Pcs/Min. Pack.)	Quantity (Pcs/Inner Box)	Quantity (Pcs/Carton)
ABS	P1	0.09	13" Reel	5000	10000	50000
ABS	P2	0.09	13" Reel	5000	10000	100000

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Recommended wave soldering condition					
Product	Peak Temperature	Soldering Time			
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds			



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(TS min) -Temperature Max(TS max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (TL) - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note: All temperatures refer to topside of the package, measured on the package body surface.

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